

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
30V	3.6mΩ@10V	32A
	4.3mΩ@4.5V	

Feature

- Split Gate Trench Technology
- Low $R_{DS(ON)}$
- Low Gate Charge
- Low Gate Resistance
- 100% UIS Tested

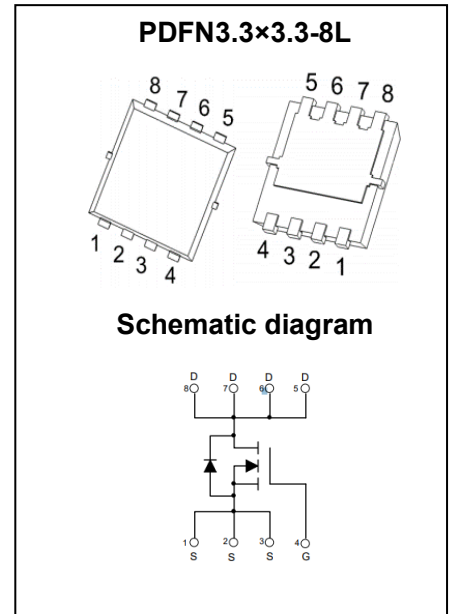
Application

- Power Switching Application

MARKING:



T039N03N = Device Code
 XX = Date Code
 Solid Dot = Green Indicator



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit	
Drain - Source Voltage	V_{DS}	30	V	
Gate - Source Voltage	V_{GS}	±20	V	
Continuous Drain Current ¹	$T_C = 25^\circ\text{C}$	I_D	32	A
	$T_C = 100^\circ\text{C}$	I_D	23	A
Pulsed Drain Current ²	I_{DM}	128	A	
Single Pulsed Avalanche Current ³	I_{AS}	29	A	
Single Pulsed Avalanche Energy ³	E_{AS}	210	mJ	
Power Dissipation ⁵	$T_C = 25^\circ\text{C}$	P_D	25	W
Thermal Resistance from Junction to Ambient ⁶	$R_{\theta JA}$	75	$^\circ\text{C/W}$	
Thermal Resistance from Junction to Case	$R_{\theta JC}$	5	$^\circ\text{C/W}$	
Junction Temperature	T_J	150	$^\circ\text{C}$	
Storage Temperature	T_{STG}	-55~ +150	$^\circ\text{C}$	

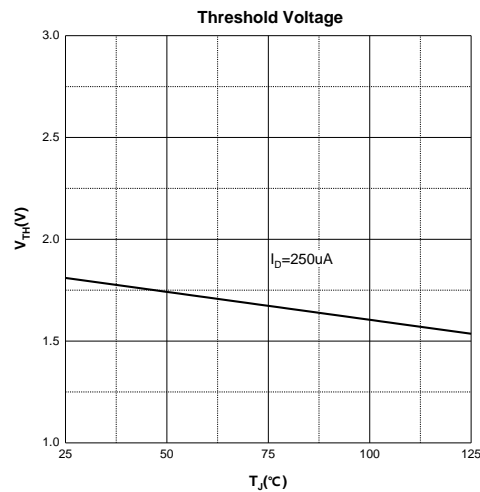
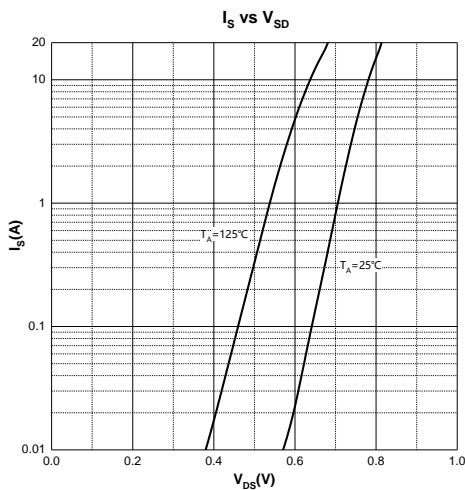
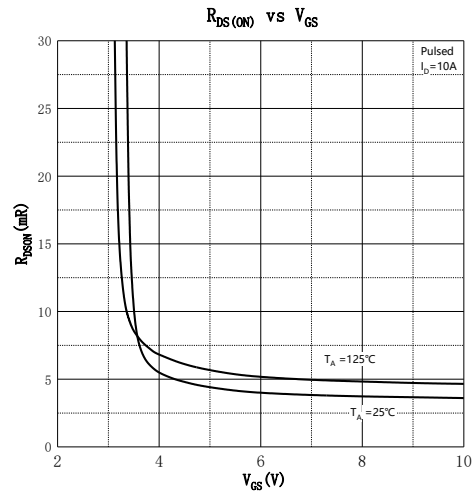
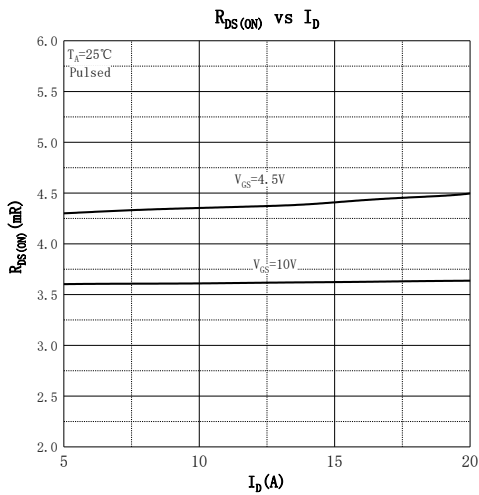
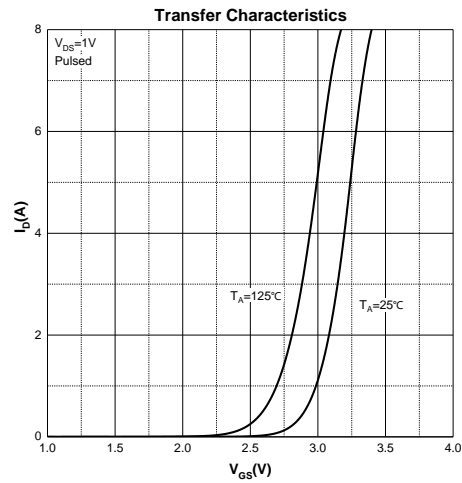
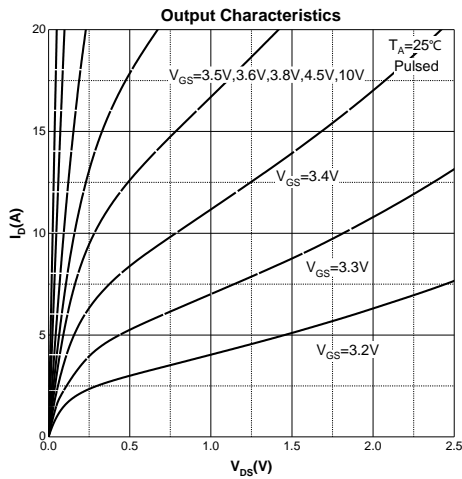
MOSFET ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

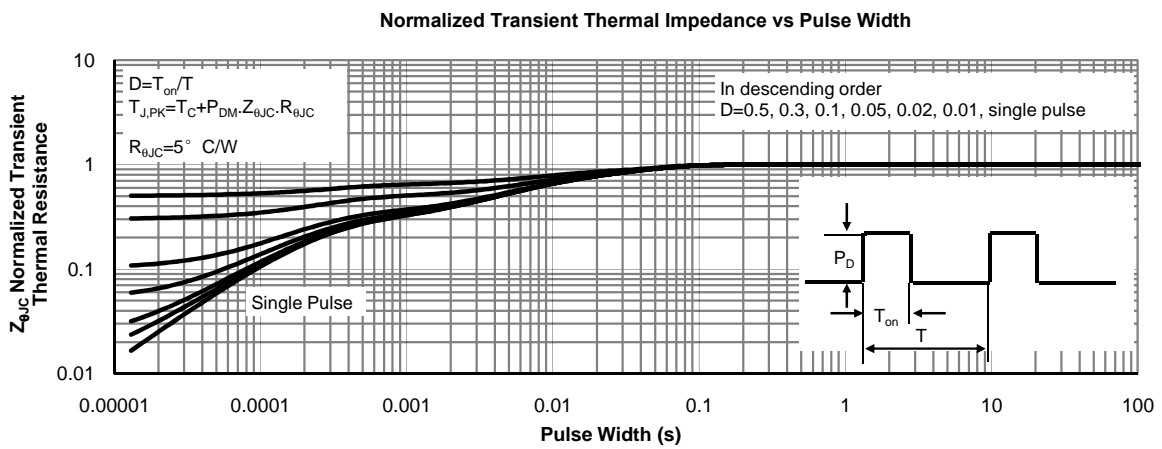
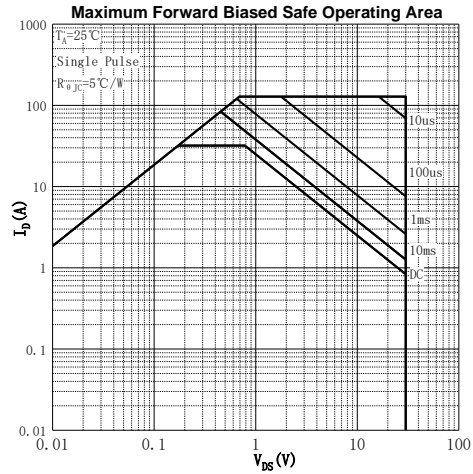
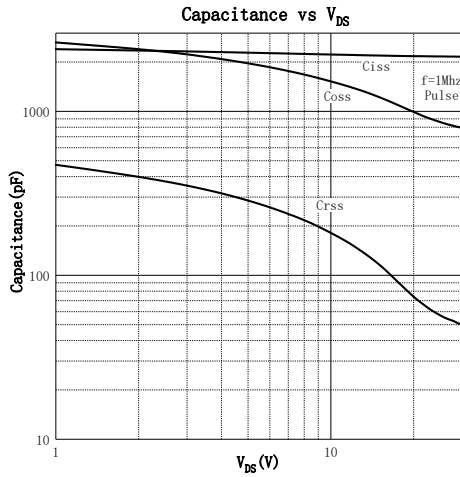
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Off Characteristics						
Drain - Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 30V, V_{GS} = 0V$			1	μA
Gate - Body Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
On Characteristics⁴						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.0	1.8	3.0	V
Drain-source On-resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 10A$		3.6	4.5	m Ω
		$V_{GS} = 4.5V, I_D = 8A$		4.3	5.9	
Forward Transconductance	g_{FS}	$V_{DS} = 10V, I_D = 10A$	10	26		S
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$		2162		pF
Output Capacitance	C_{oss}			1143		
Reverse Transfer Capacitance	C_{rss}			150		
Gate Resistance	R_g	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		3.5		Ω
Switching Characteristics						
Total Gate Charge	Q_g	$V_{DS} = 15V, V_{GS} = 10V, I_D = 10A$		37		nC
Gate-source Charge	Q_{gs}			5.2		
Gate-drain Charge	Q_{gd}			6.8		
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 15V, V_{GS} = 10V, R_L = 0.75\Omega$ $R_G = 3\Omega$		12		ns
Turn-on Rise Time	t_r			4.5		
Turn-off Delay Time	$t_{d(off)}$			30		
Turn-off Fall Time	t_f			4.5		
Source - Drain Diode Characteristics						
Diode Forward Voltage ⁴	V_{SD}	$V_{GS} = 0V, I_S = 10A$			1.2	V
Diode Continuous Forward Current ¹	I_S	$T_C = 25^\circ\text{C}$			32	A
Diode Pulse Forward Current ²	I_{SM}	$T_C = 25^\circ\text{C}$			128	A
Diode Reverse Recovery Time	t_{rr}	$I_F = 20A, di/dt = 500A/ms$		19.6		ns
Diode Reverse Recovery Charge	Q_{rr}	$I_F = 20A, di/dt = 500A/ms$		45		nC

Notes :

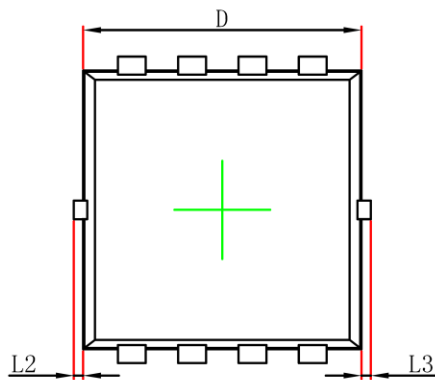
- 1.The maximum current rating is limited by package.And device mounted on a large heatsink
- 2.Pulse Test : Pulse Width $\leq 10\mu s$, duty cycle $\leq 1\%$.
- 3.EAS condition: $V_{DD} = 15V, V_{GS} = 10V, L = 0.5mH, R_G = 25\Omega$ Starting $T_J = 25^\circ\text{C}$.
- 4.Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
- 5.The power dissipation P_D is limited by $T_{J(MAX)} = 150^\circ\text{C}$.And device mounted on a large heatsink
- 6.Device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.

Typical Characteristics

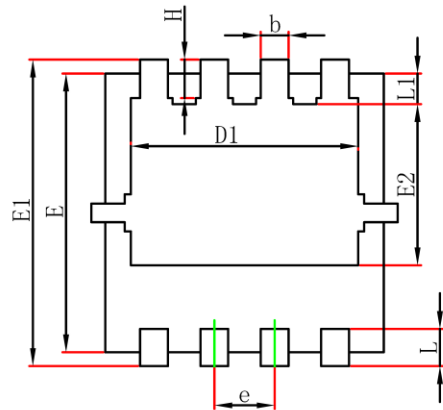




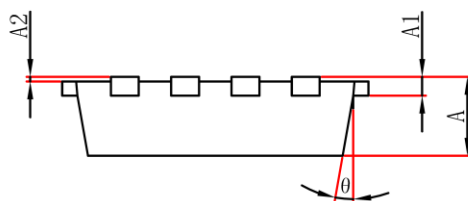
PDFN3.3×3.3-8L Package Information



Top View
[顶视图]



Bottom View
[背视图]



Side View
[侧视图]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.152REF		0.006REF	
A2	0.000	0.050	0.000	0.002
D	2.900	3.200	0.114	0.126
D1	2.300	2.600	0.091	0.102
E	2.900	3.200	0.114	0.126
E1	3.150	3.450	0.124	0.136
E2	1.535	1.935	0.060	0.076
b	0.200	0.400	0.008	0.016
e	0.550	0.750	0.022	0.030
L	0.300	0.500	0.012	0.020
L1	0.180	0.480	0.007	0.019
L2	0.000	0.100	0.000	0.004
L3	0.000	0.100	0.000	0.004
H	0.315	0.515	0.012	0.020
θ	0°	12°	0°	12°

单击下面可查看定价，库存，交付和生命周期等信息

[>>GP\(格瑞宝\)](#)